

SEMICONDUCTOR TECHNICAL DATA

KIC7WZ02FK

SILICON MONOLITHIC CMOS DIGITAL INTEGRATED CIRCUIT

2 INPUT NOR GATE

FEATURES

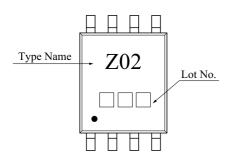
· High output drive : ± 24 mA(min.) @V_{CC}=3V.

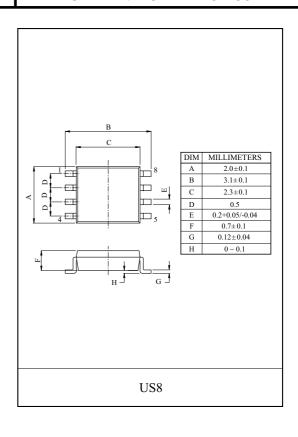
· Super high speed operation : tpd 2.4ns(typ.) @V_{CC}=5V, 50pF.

· Operation voltage range : $V_{CC(opr)}=1.65\sim5.5V$.

 \cdot Power down protection is provided on all inputs and outputs.

MARKING

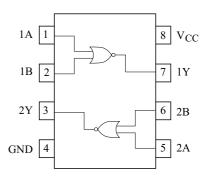




MAXIMUM RATINGS (Ta=25 °C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Power Supply Voltage	V _{CC}	-0.5~7	V
DC Input Voltage	V _{IN}	-0.5~7	V
DC Output Voltage	V _{OUT}	-0.5~7	V
Input Diode Current	I _{IK}	-50	mA
Output Diode Current	I_{OK}	-50	mA
DC Output Current	I _{OUT}	±50	mA
DC V _{CC} /ground Current	I _{CC}	±100	mA
Power Dissipation	P_{D}	200	mW
Storage Temperature Range	T _{stg}	-55 ~150	$^{\circ}$ C
Lead Temperature (10s)	$T_{ m L}$	-55 ~150	$^{\circ}$

PIN CONNECTION(TOP VIEW)

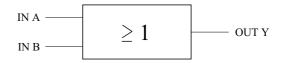


KIC7WZ02FK

Truth Table

A	В	Y
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

Logic Diagram



Recommended Operating Conditions

CHARACTERISTIC	SYMBOL	RATING	UNIT	
Supply Voltage	V _{CC}	1.65~5.5	V	
		1.5~5.5 (Note1)	•	
Input Voltage	V _{IN}	0~5.5	V	
Output Voltage	V _{OUT}	0~5.5 (Note2)	V	
		0~V _{CC} (Note3)	·	
Operating Temperature	$T_{ m opr}$	-40~85	$^{\circ}$	
Input Rise and Fall Time	$ m d_t/d_v$	$0\sim20~(V_{CC}=1.8V\pm0.15V,~2.5V\pm0.2V)$	ns/V	
		$0 \sim 10 \ (V_{CC} = 3.3V \pm 0.3V)$		
		0 ~5 (V _{CC} =5.5V ± 0.5 V)		

Note1 : Data retention only.

Note2 : $V_{CC}=0V$.

Note3: High or low state

KIC7WZ02FK

ELECTRICAL CHARACTERISTICS

DC Characteristics

CHARACTERISTIC SY		SYMBOL	TEST CONDITION		Ta=25 °C		Ta=-40~85 °C		UNIT		
		SIMBOL			V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNII
High Level	V _{IH}	-		1.65~1.95	$0.75 \times V_{CC}$	-	-	$0.75 \times V_{CC}$	-	- V	
				2.3~5.5	$0.7 \times V_{CC}$	-	-	$0.7 \times V_{CC}$	-		
Voltage	Low Level	V _{IL} -		1.65~1.95	-	-	$0.25 \times V_{CC}$	-	$0.25 \times V_{CC}$		
					2.3~5.5	-	-	$0.3 \times V_{CC}$	-	$0.3 \times V_{CC}$	
					1.65	1.55	1.65	-	1.55	-	
				I _{OH} =-100 µA	2.3	2.2	2.3	-	2.2	-	
				10H100 μΑ	3.0	2.9	3.0	-	2.9	-	
					4.5	4.4	4.5	-	4.4	-	
	High Level	V _{OH}	$V_{IN} = V_{IL}$	I _{OH} =-4mA	1.65	1.29	1.52	-	1.29	-	V
				I _{OH} =-8mA	2.3	1.9	2.15	-	1.9	-	
				I _{OH} =-16mA	3.0	2.4	2.8	-	2.4	-	
				I _{OH} =-24mA	3.0	2.3	2.68	-	2.3	-	
Output				I_{OH} =-32mA	4.5	3.8	4.2	-	3.8	-	
				I_{OH} =100 μ A I_{OH} =4mA	1.8	-	0	0.1	-	0.1	V
					2.3	-	0	0.1	-	0.1	
					3.0	-	0	0.1	-	0.1	
					4.5	-	0	0.1	-	0.1	
	Low Level	V _{OL}	$V_{IN}=V_{IH}$		1.65	-	0.08	0.24	-	0.24	
			$I_{OH}=16m$ $I_{OH}=24m$ $I_{OH}=32m$	I _{OH} =8mA	2.3	-	0.1	0.3	-	0.3	
				I _{OH} =16mA	3.0	-	0.15	0.4	-	0.4	
				I _{OH} =24mA	3.0	-	0.22	0.55	-	0.55	
				I _{OH} =32mA	4.5	-	0.22	0.55	-	0.55	
Input Leakag	-	irrent I_{IN} V_{IN} =5.5V or GND			0~5.5	-	-	±0.1	-	±10	μA
	eakage Current	I _{OFF}	V _{IN} or V _{OUT}		0.0	-	-	1	-	10	μA
Quiescent Su	ipply Current	I_{CC}	V _{IN} =5.5V o	V _{IN} =5.5V or GND		-	-	1	-	10	μA

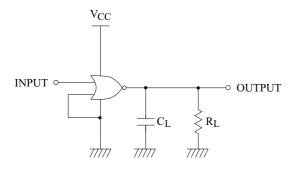
AC Characteristics (unless otherwise specified, Input : t_r = t_f =3ns)

CHARACTERISTIC SYMBO	SYMBOL	TEST CONDITIO	N	Ta=25 ℃			Ta=-40~85 °C		UNIT
	STWIDOL		V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UNII
Propagation delay time		$C_L=15pF, R_L=1M \Omega$	1.8 ±0.15	2.0	5.4	9.8	2.0	10	ns ns
			2.5 ± 0.2	1.2	3.3	5.4	1.2	5.8	
	t _{PLH} t _{PHL}		3.3 ±0.3	0.8	2.5	3.8	0.8	4.1	
			5.0 ±0.5	0.5	2.0	3.0	0.5	3.3	
		$C_L=50$ pF, $R_L=500$ Ω	3.3 ±0.3	1.2	3.1	4.6	1.2	5.0	
			5.0 ±0.5	0.8	2.4	3.7	0.8	4.0	
Input Capacitance	C _{IN}	-	0	-	2.5	-	-	-	pF
Power Dissipation Capacitance C _{PD}	(Note)	3.3	-	13.5	-	-	-	n.E	
	CPD	(Inote)	5.5	-	17.5	-	-	-	- pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + (I_{CC}^{static})$

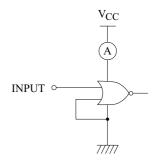
KIC7WZ02FK

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR=1.0MHz ; $t_W\!=\!\!500 ns$

FIGURE 1. AC Test Circuit



 $\begin{array}{l} \label{eq:local_problem} \mbox{Input=AC Waveform ; } t_r = & t_f = 1.8 ns \\ \mbox{PRR=10MHz ; Duty Cycle=50\%} \end{array}$

FIGURE 2. I_{CCD} Test Circuit

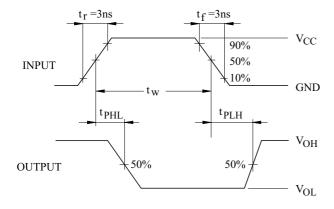


FIGURE 3. AC Waveforms